#### Stability of antiphase line defects in nanom eter-sized boron-nitride cones

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We investigate the stability of boron nitride conical sheets of nanom eter size, using rst-principles calculations. Our results indicate that cones with an antiphase boundary (a line defect that contains either B-B or N-N bonds) can be more stable than those without one. We also not that doping the antiphase boundaries with carbon can enhance their stability, leading also to the appearance of localized states in the bandgap. A mong the structures we considered, the one with the smallest form ation energy is a cone with a carbon-modi ed antiphase boundary that presents a spin splitting of 0.5 eV at the Ferm i level.

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#### I. INTRODUCTION

Boron nitride (BN) and carbon can be found in sim ilar structures, from the diam ond and graphite bulk form s, to nanostructures such as nanotubes, 1,2,3,4 fullerenes,6 and conical sheets. 7,8 However, unlike carbon, BN structures can contain three types of covalent bonds, namely B-N, N-N, and B-B.9,10 This leads to a qualitative difference between BN and carbon in the formation of the graphite-derived curved surfaces that are found in nanostructures such as fullerenes and nanotube caps. In carbon, energy minimization leads to structures made of 60 disclinations (conical sheets)<sup>11</sup> with isolated pentagons at the apex. Carbon fullerenes are built from such structures. In BN, fullerene-like structures are formed from 120 disclinations. 6 These 120 BN disclinations are usually modeled as having a four-membered ring at the apex, 6,12,13 but theoretical calculations indicate that non-stoichiom etric BN fullerenes, consisting of pentagon pairs replacing the four-mem bered rings, may be energetically favored, depending on the stoichiom etric condition of grow th.  $^{14,15}$ 

A possible reason for the existence of 120 disclinations in BN nanostructures, instead of the 60 ones that are found in carbon, is the existence of antiphase boundaries (APB) in BN disclinations with an odd multiple of 60. 16,17 The common perception is that these APB's, which necessarily contain a line defect of non-BN bonds, should present an energy cost that surpasses the lower elastic-energy cost of a disclination of smaller angle. However, such a \no-wrong-bond" rule<sup>13</sup> has been challenged by at least two experiments. In their work, Bourgeois et al.8 have shown the existence of BN conical nanostructures with a disclination angle of 300, dem onstrating the existence of APB's. A nother example in the literature is the observation of disclinations in BN nanotube junctions, 18 in experim ents whose interpretation is also compatible with the existence of an APB.

In the present work, we investigate the relative stability of nanometer-sized BN cones with and without

APB's, for N-rich and B-rich environments. Our rst-principles results indicate that, for these two limiting stoichiometric situations, structures with an APB can be more stable than APB-free structures, consisting only of B-N bonds. We also not structures involving full carbon incorporation at the APB to be among the most stable, under both environments.

The paper is organized as follows: in Sec. II we discuss the ab initio methodology for the computation of the total energies and the denition of chemical potentials for the computation of the zero-Kelvin grand potentials; in Sec. III we discuss our model for the formation energy as a sum of antiphase boundary and elastic energies; in Sec. IV we discuss our rst principles results for the relative stability of the various cones and some features of the electronic states of the most stable structures; and nally, in Sec. V we present some discussion of scaling to larger structures than considered in this work and conclusions.

#### II. M ETHODOLOGY

### A. Total energy calculations

Our calculations are based on the density functional theory  $^{19}$  as implemented in the SIESTA program  $^{20}$  We make use of norm-conserving Troullier-Martins pseudopotentials  $^{21}$  in the K leinman-Bylander factorized form,  $^{22}$  and a double-basis set composed of numerical atom is orbitals of nite range. Polarization orbitals are included for nitrogen, boron and carbon atoms, and we use the generalized gradient approximation (GGA) $^{23}$  for the exchange-correlation potential. All the geometries are fully relaxed, with residual forces smaller than 0.1 eV/A.

#### B. Zero-Kelvin grand potentials

The comparison of BN clusters with dierent number of atoms is a dicult problem. Here, we propose a zero-tem perature them odynamic approach based on the prior determination of themical potentials to address this issue. The robustness of the approach will be established by comparison with results obtained with dierent themical potentials, which represent dierent experimental conditions, and with similar calculations in the literature. 14,24,25,26,27

In order to address the energetics of stoichiom etric and nonstoichiom etric cones, we must distinguish the dierent techniques that can be employed in their synthesis. In each case, we introduce suitable theoretical chemical potentials for nitrogen ( $_{\rm N}$ ) and boron ( $_{\rm B}$ ). For the case in which the cones are obtained by laser ablation or arc-discharge from hexagonal BN, we can have either a nitrogen-or a boron-rich environment, depending on the speci c atom ic reservoir employed. In the N-rich environment,  $_{\rm N}$  is obtained from nitrogen in the gas phase, while a metallic -B phase is used as the reservoir for the B-rich environment. In both cases,  $_{\rm N}$  and  $_{\rm B}$  are linked by the therm odynam ic constraint

$$_{N}$$
 +  $_{B}$  =  $_{BN}^{layer}$ ; (1)

where  $_{\rm B\,N}^{\rm layer}$  is the chem ical potential per BN pair in the in nite, planar BN sheet. This constraint corresponds to situations in which the nanostructures are formed in equilibrium with BN layers. Since we are dealing with nite clusters, we use hydrogen atoms to saturate the dangling bonds at the edges. To take these additional H-B and H-N bonds into account, we introduce the respective chemical potentials,  $_{\rm H\,B}$  and  $_{\rm H\,N}$ , and write the formation energy of the cones as

$$E_{form} = E_{tot} n_{B B} n_{N N} n_{H N H N}$$

$$n_{H B H B}; \qquad (2)$$

where  $E_{tot}$  is the calculated total energy of the cluster,  $n_B$  and  $n_N$  are the number of B and N atoms, and  $n_{H\,N}$  and  $n_{H\,B}$  are the number of H-B and H-N bonds, respectively. The formation energy, as dened in Eq. 2, represents the zero-K elvin grand potential which is the proper thermodynamical potential for the comparison of the relative stability of structures with dierent number of atoms.

A rst constraint on the hydrogen chem ical potentials is in posed by using a nite planar sheet of boron nitride as reference, and ascribing a null value to its form ation energy. This allows us to write its total energy as

$$\mbox{E}_{\mbox{\scriptsize T}}^{\mbox{\scriptsize sheet}} = \mbox{\mbox{$n$}}_{\mbox{\scriptsize B}\mbox{\scriptsize N}}^{\mbox{\scriptsize layer}} + \mbox{\mbox{$n$}}_{\mbox{\scriptsize H}\mbox{\scriptsize B}} + \mbox{\mbox{$n$}}_{\mbox{\scriptsize H}\mbox{\scriptsize N}} + \mbox{\mbox{$n$}}_{\mbox{\scriptsize H}\mbox{\scriptsize N}} \mbox{\mbox{\mbox{\scriptsize H}}}_{\mbox{\scriptsize N}} \mbox{\mbox{\mbox{\scriptsize $N$}}} \mbox{\mbox{\mbox{\scriptsize $N$$$

where  $n_{RN}$  is the number of BN pairs.

The planar reference sheet is centered at a sixfold ring and has C  $_{3v}$  sym m etry. Therefore,  $n_{\rm H~B}$  =  $n_{\rm H~N}$  and the

preceding equation can be rewritten as

$$E_{T}^{\text{sheet}} = n_{BN} \quad _{BN}^{\text{layer}} + n_{H} \quad _{H} \quad ; \tag{4}$$

where we have de ned  $_{\rm H}$  =  $_{\rm B\,H}$  +  $_{\rm N\,H}$  =2. Using the total energy calculations for the in nite layer and the nite sheet, we nd  $_{\rm H}$  = 15:46 eV .

From the de nition of  $_{\rm H}$  , we obtain  $_{\rm H\ B}$  (  $_{\rm H\ N}$  ) once  $_{\mbox{\scriptsize H~N}}$  (  $_{\mbox{\scriptsize H~B}}$  ) is known. The values of one of these param – eters can be determ ined by choosing a convenient reservoir. In our calculations we use the amm onia molecule  $(NH_3)$  as a reservoir, obtaining  $_{HN}$  = 16:16 eV and  $_{\rm H~B}$  = 14:76 eV in the N -rich environm ent, and  $_{\rm H~N}$  = 15:23 eV and  $_{\rm H~B}$  = 15:69 eV in the B-rich environm ent. The consistency of this m ethodology was tested by determ ining  $_{\rm H\ B}$  using the BH  $_{\rm 3}$  m olecule as a reservoir, and then calculating  $_{\rm H\ N}$  from  $_{\rm H}$  . The calculated formation energies in this case are within 0:01 eV/atom of those from the NH3 reservoir. For the structures containing carbon, the chem ical potentials for the carbon atom (  $_{\rm C}$  ) and the carbon-hydrogen bonds (  $_{\rm C,H}$  ) are obtained from total energy calculations for bulk graphene and for a nite carbon sheet saturated by hydrogen atom s, respectively.

# III. FORM AT ION ENERGY: ANTIPHASE-BOUNDARY AND ELASTIC CONTRIBUTIONS

The physical mechanism that de nes whether structures having APB's may be as stable as their APB-free counterparts is the competition between the elastic energy associated with the cone formation and the energetic cost of forming an APB. Hence, we write the cone formation energies, calculated with the above procedure, as the sum of two contributions. The rst is the elastic energy required to fold a nite sheet into a cone, which we describe by a continuum model. The second represents the APB chemical energetic cost associated with the non-BN bonds.

The basic assumption of the continuum model is that the elastic energy stored in a dierential element of area at the surface of the cone is proportional to the square of the surface mean curvature in that region. Within this model, the elastic energy of the cone is written

$$E_{el} = K \frac{\cos^2}{\sin^2 \theta} \ln \frac{R}{R_c} + E_{tip}(R_c); \qquad (5)$$

where 2 is the apex angle, R is the slant height, R  $_{\rm C}$  is a cuto length introduced to rem ove the singularity at the tip (linear elasticity breaks down in the neighborhood of the tip), and E  $_{\rm tip}$  (R  $_{\rm C}$ ) is the associated tip energy. The expression

$$\sin(1) = 1 \frac{1}{2} = 1 \frac{N}{6}$$
 (6)

relates the apex angle to the disclination angle  $\,=\,N$ 

The validity of the continuum model was sixt tested for the case of carbon, for which there is no APB. We found that the six-principles total energy calculations for the graphene sheet, and for the cones with 60 and 120 disclinations are tred remarkably wellby a straight line, when plotted as a function of  $\cos^2 = \sin$ , as shown in Fig. 1. This fact also shows that there is no tip con-

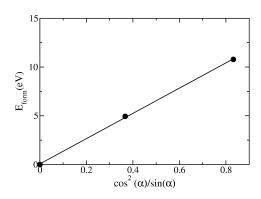


FIG. 1: Formation energy as a function of  $\cos^2 = \sin$  for carbon cones with 60 and 120 disclinations and for the graphene sheet.

tribution to the form ation energy, i.e. E $_{\rm tip}=0$ , at least for structures with disclination angles up to 120 . This can be explained by the fact that these geom etries have the general appearance of truncated cones. Figure 1 also allows us to consider that R $_{\rm c}$  is the same for the cones with 60 and 120 disclinations.

Adding the APB energies, we write

$$E_{form} = K - \frac{\cos^2}{\sin} - \ln \frac{R}{R_c} + E_{APB};$$
 (7)

for the form ation energy of BN cones. The constant of proportionality K can be obtained  $\sin p \ln p \cos considering$  that for a 120 disclination there is no APB, hence  $E_{APB} = 0.28$  Having K and the form ation energies, we can use the equation above to estimate the APB energies.

### IV. FIRST PRINCIPLES RESULTS

Figure 2 shows three of the most stable structures found in our study. Note that each contains a 60 disclination, leading to the form ation of an APB.We considered two kinds of APB's: one contains a sequence of parallel (N-N orB-B) bonds, as shown in Figs. 2 (a) and 2 (c), and the other a sequence of zig-zag (N-N orB-B) bonds. These are denoted molecular APB and zig-zag APB, respectively. For cones with 120 disclinations, we considered structures with a four-mem bered ring at the apex (without non-BN bonds), as well as structures with two pentagons at the apex, adjacent or not. Disclinations of

180 and 300 (each containing an APB) were also addressed. To make contact with experimental results for the synthesis of BN cones from carbon templates, we also considered the possibility of carbon incorporation in BN cones, leading to the formation of carbon zig-zag [shown in Fig. 2(e)] and molecular APB's. In these structures, every (B or N) atom along the APB is replaced by a carbon atom .

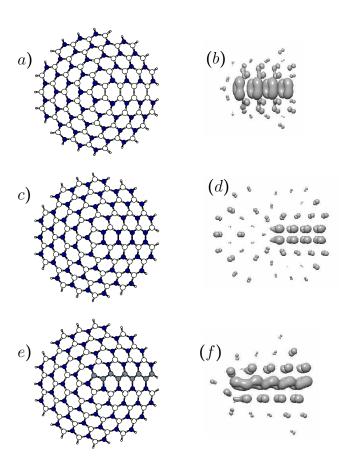


FIG. 2: (Color on line) Stable boron nitride nanom eter-sized conical structures with 60 disclinations and an APB (see text). Boron, carbon, and nitrogen atoms are represented by white, gray, and black (blue) circles, respectively. Hydrogen atoms saturate the dangling bonds at the edges. (a) and (b) show a molecular APB of boron and the electron distribution of its empty gap states, respectively. (c) and (d) show the same for a nitrogen molecular APB and its lled gap states. (e) and (f) show the same for a zig-zag APB of carbon and its lled gap states.

Our st principles results for the formation energy of cones with various disclination angles, for B-rich and N-rich environments, are shown in Table I. For the 60 - disclination cones, the third and fourth columns of Table I show the ratio  $E_{APB}=E_{el}$ , where  $E_{el}=2.96$  eV, from the continuum model. Note that the highest APB energies are associated with zig-zag congurations, more specifically a zig-zag boron APB in the N-rich environment, and a zig-zag nitrogen APB in the B-rich environment. Geometric aspects may explain these results. In-

deed, zig-zag APB's introduce larger strains in the structures when compared to molecular APB's, since the parallel arrangement of B-B and N-N bonds in the latter is more easily accommodated by the BN matrix of the cone. Table I also shows that for some structures the energetic cost of creating an APB is comparable to the elastic energy, i.e.  $E_{\rm APB} = E_{\rm el}$  1. For the B-rich environment, these are the molecular APB of boron [shown in Fig. 2(a)] and the zig-zag APB of carbon (with C-B bonds), while for the N-rich environment, the ratio is 1 for the molecular APB of nitrogen [shown in Fig. 2(c)] and the zig-zag APB of carbon (with C-N bonds) [shown in Fig. 2(e)]. From these observations, we expect that cones with these APB's will be the best candidates to compete energetically with APB-free cones.

Our results for the form ation energies, shown in the last two columns of Table I, con mm this expectation. As discussed in Ref. 14, in a condition of chem ical equilibrium, the relative stability of the structures is determined by the quantity  $E_{\text{form}} = n_{\text{poor}}$ , where  $n_{\text{poor}}$  is the number of atoms of the species for which the environment is poor  $[n_B]$   $(n_N)$  in the N-rich (B-rich) case]. The underlined numbers in Table I indicate the most stable structures. A general trend that can be inferred from the numbers in table I is that the existence of non B-N bonds does not necessarily increase the formation energy. The stability of non-stoichiometric cones depends strongly on the environment. This conclusion is valid for isolated non B-N bonds as well as for the dierent kinds of APB's.

Concentrating on the structures with 120 disclinations, we note that, under N-rich conditions, the energy of a cone with two non-adjacent pentagons (containing three N-N bonds) is comparable to that of a cone with a four-membered ring at the apex. The same is true if the pentagons are adjacent. The latter is a stoichiom etric structure with only one non-BN bond, and its form ation energy is independent of the environment.

Concerning the APB's in geom etries with 60 disclinations, we remark again that under the two limiting stoichiom etric conditions we considered, 60 disclinations with  $E_{APB} = E_{el}$  1 [the molecular APB of nitrogen (in the N-rich case) and the molecular APB of boron (in the B-rich case)] can be more stable than the APB-free structures with 120 disclinations. These are stable structures, despite being responsible for the existence of gap states. <sup>16</sup> (G ap states are absent in the case of cones with a 120 disclination.)

The electronic charge densities associated with the gap states for the molecular APB's of boron and nitrogen are shown in Figs. 1(b) and 1(d), respectively. The nitrogen-APB states show a substantial degree of delocalization, spreading over the BN matrix of the cone, while the boron-APB states remain strongly localized on the B atoms at the APB. In a previous study, 16 we exam ined the electronic levels of these two structures. In the nitrogen case, we found that three fully occupied levels appear in the lower half of the gap, and Fig. 1(d) shows that they have the same nitrogen lone-pair char-

TABLE I: Form ation energies (in eV) of stoichiom etric and non-stoichiom etric cones, for N-rich and B-rich environm ents. The rst column indicates the disclination angle for each structure. Second column indicates either the type of APB or the topological defect at the apex, in each case. For the 120 and 180 disclinations, we considered dierent possibilities for the defect at the apex (indicated by the number of squares and pentagons in each case). The third and fourth columns show the ratio between the the antiphase-boundary (EAPB) and elastic energies (Eel) for the 60 disclinations. The last two columns show the form ation energy per  $n_{\rm poor}$ , as discussed in the text. Underlined numbers indicate the most stable structures for each environment.

| D iscl | . Cone                      | E <sub>APB</sub><br>E <sub>e1</sub> | E <sub>APB</sub><br>E <sub>el</sub> | E form<br>n (B) | E form<br>n (N ) |
|--------|-----------------------------|-------------------------------------|-------------------------------------|-----------------|------------------|
|        |                             | (N-rich)                            | (B-rich)                            | (N-rich)        | (B-rich)         |
| 120    | 1 sq.                       |                                     |                                     | 0.15            | 0.15             |
| 120    | 2 pent.                     |                                     |                                     | 0.17            | 0.30             |
| 120    | 2 ad. pent.                 |                                     |                                     | 0.12            | 0.14             |
| 60     | Z ig-N                      | 2.9                                 | 7.9                                 | 0.21            | 0.44             |
| 60     | Z.ig-B                      | 7.7                                 | 2.7                                 | 0.43            | 0.20             |
| 60     | M ol-B                      | 3.8                                 | 1.3                                 | 0.24            | 0.12             |
| 60     | $M 	ext{ ol-}N$             | 1.1                                 | 3.8                                 | 0.11            | 0.24             |
| 60     | Zig-C (C-B)                 | 4.4                                 | 1.2                                 | 0.29            | 0.13             |
| 60     | Z ig - C (C - N)            | 0.6                                 | 3.8                                 | <u>0.09</u>     | 0.26             |
| 60     | $M 	ext{ ol-} C 	ext{-} B)$ | 7.1                                 | 2.1                                 | 0.43            | 0.18             |
| 60     | $M \circ HC (C -N)$         | 1.4                                 | 6.0                                 | 0.14            | 0.37             |
| 180    | 3 pents                     |                                     |                                     | 0.48            | 0.85             |
| 180    | 1 pent. + 1 sq.             |                                     |                                     | 0.42            | 0.66             |
| 300    | M ol-N                      |                                     |                                     | 1.44            | 1.61             |

acter that dom inates the states at the top of the valence band of the cone. This leads to a strong m ixing between the APB states and the valence-band states in the bulk of the cone, this being the reason for the delocalized character of the nitrogen-APB states. In the case of boron, the states shown in Fig. 1 (b) are empty levels near the bottom of the conduction band. They have a more metallic character, diering from the states at the bottom of the conduction band. Mixing is absent in this case, leading to the localized distribution seen in Fig. 1 (b).

Table I also shows that cones with zig-zag APB's have higher form ation energies, and the same occurs for structures with large disclination angles. The result is expected in the case of the 180 and 300 disclinations, since besides the cost of form ing an APB, the elastic energy is also large. However, we note that these metastable structures have already been found experimentally.  $^{\!8,18}$ 

Regarding carbon-doped cones, we nd that incorporation of carbon at the APB leads to highly stable structures. In this case, for both kinds of APB's the most stable structures are those where the APB is connected to the BN m atrix by C-N (C-B) bonds in the N-rich (B-rich) environment. A ctually, the most stable of all structures in our study is the C-N connected carbon zig-zag APB, in the N-rich environment, shown in Fig. 1 (e). The elec-

tronic charge density of the gap states associated with this structure is shown in Fig. 1 (f). The states are predom inantly localized in the antiphase boundary, strongly resembling the states characteristic of the graphite band. This wavefunction localization leads also to a considerable spin splitting at the Fermilevel. For the neutral charge state, the energy di erence between the highest-occupied molecular orbital (which has majority spin) and the lowest-unoccupied one (which has minor-0:5 eV. This spin splitting appears only ity spin) is for structures with an odd number of electrons, a result that raises the interesting question about what may happen in the lim it of cones with larger sizes. Furtherm ore, we have also identi ed a tendency for carbon atoms to segregate at the APB. In our calculations, a single pair of carbons atoms is found to be more stable (by 0.07-0.15 eV/atom) on the APB than in the bulk of a BN cone. This may indicate a tendency for the form ation of these carbon-modi ed APB's, during the synthesis of BN conical nanostructures by substitution on a carbon tem plate.

Boron nitride cones can also be obtained by a substitution reaction 18 on a carbon template in which B<sub>2</sub>O<sub>3</sub> and gaseous N2 are used as sources of boron and nitrogen, respectively. To check the stability trends in this case, we consider that BN cones and CO2 are the byproducts of this reaction. The nitrogen and boron chem ical potentials are then obtained in terms of the total energies of the species involved. 29 W ith this procedure, the value we obtained for the chemical potential dier- $_{\rm B}$  = 189:936 eV, is very close to the value of-190,126 eV, obtained for an N-rich environm ent under the constraint in Eq. 1. Therefore, the stability trends shown in table I still hold in this case. We also checked the robustness of our results with respect to changes in the boundary conditions, which could happen, for instance, if the cones were interacting with dierent surfaces. This was done by imposing a constant shift of

0.5 eV on all hydrogen chem ical potentials. The ordering of the quantities  $E_{form} = n_{poor}$  in table I remains unaltered, with relative shifts of less than 0.02 eV. Still to conm the validity of our methodology, we mention that similar approaches have been employed in the literature in the determination of formation energies of defects in cubic boron nitride,  $^{24,25,26}$  in boron nitride nanotubes and in the investigation of possible structures of boron nitride fullerenes. In the latter work, the stability trends

obtained by using the solid phases of boron and nitrogen together with the constraint in Eq. 1 remained largely unchanged when the authors considered the gas phase limit of atomic reservoirs.

## V. REMARKS ON SIZE SCALING AND CONCLUSION

Finally, we discuss the relevance of our results in face of the expected scaling trends. As the size of a cone increases, the APB energy scales linearly with the slant height R (see Eq. 5), i.e. with the square root of the total number of atoms in the structure, while the elastic energy scales sub-linearly with R, as shown in Eq. 5. Hence, structures without APB's become energetically favored for su ciently larger sizes. However, cones of the size we consider in this work may represent the seeds present in the initial steps of the nucleation process that generates larger cones or other nanostructures. Not only the energetics, but also kinetics play an important role in this process, and to the extent that we may expect low energy con gurations to be favored for the seeds, cones with certain types of APB's may be good candidates, and kinetics may determine the formation of larger size structures containing APB's.

To sum marize, we used rst-principles calculations to address the question of how stable are antiphase boundaries in boron nitride nanom eter-sized conical nanostructures. Our results indicate that 60 disclinations with an APB can be more stable than APB-free 120 disclinations. We show that the form ation energies of the stable APB's are comparable to the disclination elastic energy, and that the dependence of the latter on the disclination angle is very well described by a continuum model. Also, we observe that carbon incorporation at the APB leads to highly stable structures, of which the most stable presents a large spin splitting (0.5 eV) at the Ferm i level.

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- There is a very small dierence in slant height between our 60 - and 120 -disclination structures, which leads to a negligible change in the logarithm ic term in Eq.5 between these two types of structures. This has been neglected in our determination of K.
- The substitution reaction described allows us to write the nitrogen and boron chem ical potentials as  $_{\rm N}=\frac{1}{2}$  E (N  $_2$ ) and  $_{\rm B}=\frac{1}{2}$  E (B  $_2$ O  $_3$ ) +  $\frac{3}{2}$ E (C)  $-\frac{3}{2}$ E (CO  $_2$ )], where E (N  $_2$ ) and E (CO  $_2$ ) are the total energies of the nitrogen and carbon dioxide m olecules, respectively, E (B  $_2$ O  $_3$ ) is the total energy of a planar hexagonal B  $_2$ O  $_3$  structure and E (C) is the energy per atom in graphene. All these quantities are obtained by means of rst-principles calcultions and the resulting values of  $_{\rm N}$  and  $_{\rm B}$  are -270.151 eV and -80.214 eV, respectively.